NSN 5962-01-058-6774

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Body Length:
Between 0.370 inches and 0.434 inches
Body Width:
Between 0.240 inches and 0.285 inches
Body Height:
Between 0.049 inches and 0.090 inches
Maximum Power Dissipation Rating:
680.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set type an/aps-125
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/open collector and w/enable and w/disable and w/storage and bipolar and
programmable and programmed and w/buffered output and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
90.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
27963-57991000 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Unit Of Measure:

16 flat leads

Shelf Life:

N/a

Terminal Type And Quantity:

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Demilitarization:

Yes - demil/mli

Fiig:

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